NSN 5961-01-209-1861

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-209-1861		
Inclosure Material:		
Plastic		
Overall Length:		
0.315 inches		
Terminal Length:		
0.327 inches		
Overall Height:		
0.190 inches		
Overall Width:		
0.400 inches		
Internal Configuration:		
Junction contact		
Mounting Method:		
Terminal		
Semiconductor Material:		
Silicon		
Voltage Rating In Volts Per Characteristic:		
400.0 forward voltage, peak and 400.0 working peak reverse voltage, p	peak total value,	gate terminal open-circuited
Current Rating Per Characteristic:		
75.00 amperes forward current, total rms torr		
Power Rating Per Characteristic:		
0.5 watts small-signal input power, common-collector blank		
Maximum Operating Tempurature Per Measurement Point:		
110.0 degrees celsius junction		
Special Features:		
Junction pattern arrangement: pnpnp		
Terminal Type And Quantity:		
3 uninsulated wire lead		
Shelf Life:		
N/a		
Unit Of Measure:		
Demilitarization:		
No		
Fiig:		
A110a0		